

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China







Preferred Device

Self-Protected FET with Temperature and Current Limit

42 V, 2.0 A, Single N-Channel, SOT-223

HDPlus[™] devices are an advanced series of power MOSFETs which utilize ON Semiconductors latest MOSFET technology process to achieve the lowest possible on–resistance per silicon area while incorporating smart features. Integrated thermal and current limits work together to provide short circuit protection. The devices feature an integrated Drain–to–Gate Clamp that enables them to withstand high energy in the avalanche mode. The Clamp also provides additional safety margin against unexpected voltage transients. Electrostatic Discharge (ESD) protection is provided by an integrated Gate–to–Source Clamp.

Features

- Current Limitation
- Thermal Shutdown with Automatic Restart
- Short Circuit Protection
- I_{DSS} Specified at Elevated Temperature
- Avalanche Energy Specified
- Slew Rate Control for Low Noise Switching
- Overvoltage Clamped Protection
- Pb-Free Packages are Available

Applications

- Lighting
- Solenoids
- Small Motors

MAXIMUM RATINGS (T_J = 25°C unless otherwise noted)

Rating	Symbol	Value	Unit	
Drain-to-Source Voltage Internally Clamped	V_{DSS}	42	V	
$\begin{array}{c} \text{Drain-to-Gate Voltage Internally Clamped} \\ (\text{R}_{G} = 1.0 \text{M}\Omega) \end{array}$	V _{DGR}	42	V	
Gate-to-Source Voltage	V _{GS}	± 14	V	
Continuous Drain Current	I _D	Internally Limited		
Power Dissipation @ $T_A = 25^{\circ}C$ (Note 1) @ $T_A = 25^{\circ}C$ (Note 2) @ $T_T = 25^{\circ}C$ (Note 3)	P _D	1.1 1.7 8.9	W	
Operating Junction and Storage Temperature	T _J , T _{stg}	–55 to 150	°C	
	E _{AS}	150	mJ	

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

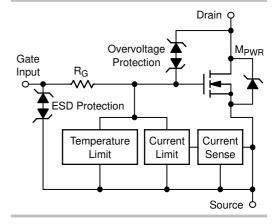


ON Semiconductor®

http://onsemi.com

V _{(BR)DSS} (Clamped)	R _{DS(ON)} TYP	I _D MAX
42 V	165 mΩ @ 10 V	2.0 A*

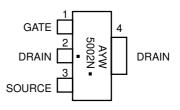
*Max current limit value is dependent on input condition.





SOT-223 CASE 318E STYLE 3

MARKING DIAGRAM



A = Assembly Location

Y = Year

W = Work Week

5002N = Specific Device Code

= Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 4 of this data sheet.

Preferred devices are recommended choices for future use and best overall value.

THERMAL CHARACTERISTICS

Characteristic	Symbol	Value	Unit
Junction-to-Ambient - Steady State (Note 1) Junction-to-Ambient - Steady State (Note 2) Junction-to-Tab - Steady State (Note 3)	$R_{ hetaJA} \ R_{ hetaJA} \ R_{ hetaJT}$	114 72 14	°C/W

- Surface-mounted onto min pad FR4 PCB, (2 oz. Cu, 0.06" thick).
 Surface-mounted onto 2" sq. FR4 board (1" sq., 1 oz. Cu, 0.06" thick).
 Surface-mounted onto min pad FR4 PCB, (2 oz. Cu, 0.06" thick).

ELECTRICAL CHARACTERISTICS ($T_J = 25$ °C unless otherwise noted)

Parameter	Symbol	Test Condition		Min	Тур	Max	Unit
OFF CHARACTERISTICS	1	l			1	1	l
Drain-to-Source Breakdown Voltage	V _{(BR)DSS}		T _J = 25°C	42	46	55	V
(Note 4)		$V_{GS} = 0 \text{ V}, I_{D} = 10 \text{ mA}$	T _J = 150°C	40	45	55	1
Zero Gate Voltage Drain Current	I _{DSS}		T _J = 25°C		0.25	4.0	μΑ
		$V_{GS} = 0 \text{ V}, V_{DS} = 32 \text{ V}$	T _J = 150°C		1.1	20	
Gate Input Current	I _{GSSF}	V _{DS} = 0 V, V _{GS} =	5.0 V		50	100	μΑ
ON CHARACTERISTICS (Note 4)	•				•	•	
Gate Threshold Voltage	V _{GS(th)}	$V_{GS} = V_{DS}, I_D = 15$	50 μΑ	1.3	1.8	2.2	V
Gate Threshold Temperature Coefficient	V _{GS(th)} /T _J				4.0	6.0	–mV/°C
Static Drain-to-Source On-Resistance	R _{DS(on)}	V 40V 1 47A	$T_J = 25^{\circ}C$		165	200	mΩ
		$V_{GS} = 10 \text{ V}, I_D = 1.7 \text{ A}$	T _J = 150°C		305	400	
		V 50VI 17A	$T_J = 25^{\circ}C$		195	230	
		$V_{GS} = 5.0 \text{ V}, I_D = 1.7 \text{ A}$	T _J = 150°C		360	460	
		V 50VI 05A	T _J = 25°C		190	230	
		$V_{GS} = 5.0 \text{ V}, I_D = 0.5 \text{ A}$	T _J = 150°C		350	460	
Source-Drain Forward On Voltage	V _{SD}	V _{GS} = 0 V, I _S = 7.0 A			1.0		٧
SWITCHING CHARACTERISTICS							
Turn-on Time	t _{d(on)}	V _{GS} = 10 V, V _{DD} =			20	30	μs
Turn-off Time	t _{d(off)}	$I_D = 2.5 \text{ A}, R_L = 4.7 \Omega,$ (10% V_{in} to 90% I_D)			65	100	
Slew Rate On	dV _{DS} /dt _{on}	R _L = 4.7 Ω, V _{in} = 0 to 10 V, V _{DD} = 12 V, 70% to 50%			1.2		V/μs
Slew-Rate Off	dV _{DS} /dt _{off}	$R_L = 4.7 \ \Omega, \ V_{in} = 0 \text{ to } 10 \ V, \ V_{DD} = 12 \ V, 50\% \text{ to } 70\%$			0.5		
SELF PROTECTION CHARACTERISTICS	S (T = 25°C)	ınless otherwise noted) (No	ite 5)		ı	1	1
Current Limit	I _{LIM}		T _{.1} = 25°C	3.1	4.7	6.3	Α
		$V_{DS} = 10 \text{ V}, V_{GS} = 5.0 \text{ V}$	T _J = 150°C	2.0	3.2	4.3	
			T _{.1} = 25°C	3.8	5.7	7.6	
		$V_{DS} = 10 \text{ V}, V_{GS} = 10 \text{ V}$	T _J = 150°C	2.8	4.3	5.7	
Temperature Limit (Turn-off)	T _{LIM(off)}	V _{GS} = 5.0 V		150	175	200	°C
Temperature Limit (Circuit Reset)	T _{LIM(on)}	V _{GS} = 5.0 V		135	160	185	
Temperature Limit (Turn-off)	T _{LIM(off)}	V _{GS} = 10 V		150	165	185	1
Temperature Limit (Circuit Reset)	T _{LIM(on)}	V _{GS} = 10 V		135	150	170	1
ESD ELECTRICAL CHARACTERISTICS	, ,			1	1	1	II.
Electro-Static Discharge Capability			(HBM)	4000			V
		Machine Model (MM)		400			1

- 4. Pulse Test: Pulse Width ≤ 300 μs, Duty Cycle ≤ 2%.
 5. Fault conditions are viewed as beyond the normal operating range of the part.

TYPICAL PERFORMANCE CURVES

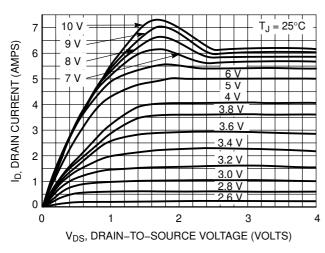


Figure 1. On-Region Characteristics

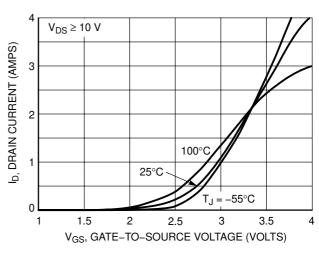


Figure 2. Transfer Characteristics

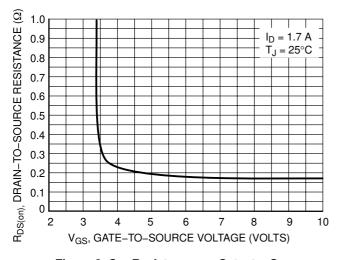


Figure 3. On-Resistance vs. Gate-to-Source Voltage

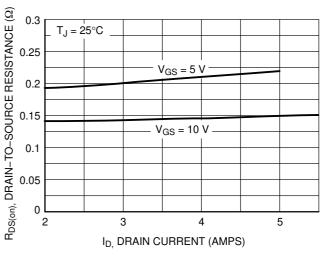


Figure 4. On–Resistance vs. Drain Current and Gate Voltage

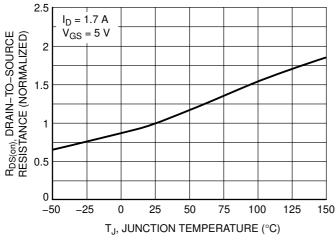


Figure 5. On–Resistance Variation with Temperature

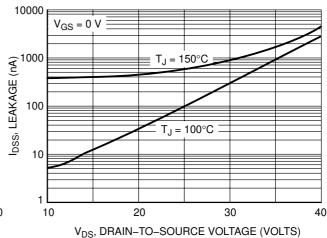
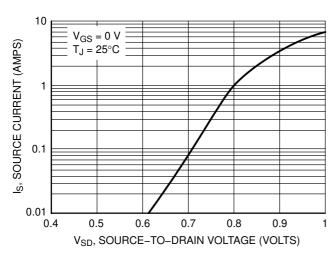


Figure 6. Drain-to-Source Leakage Current vs. Voltage

TYPICAL PERFORMANCE CURVES



1.0 V_{GS} = 20 V SINGLE PULSE T_C = 25°C 1 ms 10 ms 1

Figure 7. Diode Forward Voltage vs. Current

Figure 8. Maximum Rated Forward Biased Safe Operating Area

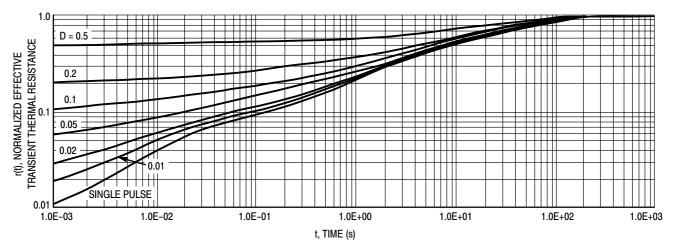


Figure 9. Thermal Response

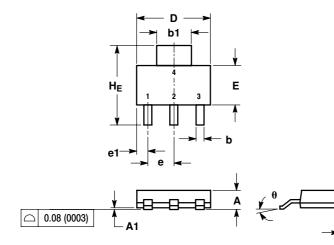
ORDERING INFORMATION

Device	Package	Shipping [†]
NIF5002NT1	SOT-223	1000 / Tape & Reel
NIF5002NT1G	SOT-223 (Pb-Free)	1000 / Tape & Reel
NIF5002NT3	SOT-223	4000 / Tape & Reel
NIF5002NT3G	SOT-223 (Pb-Free)	4000 / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

PACKAGE DIMENSIONS

SOT-223 (TO-261) CASE 318E-04 ISSUE L



NOTES

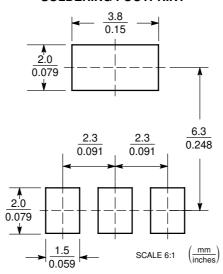
- 1. DIMENSIONING AND TOLERANCING PER ANSI
 - Y14.5M, 1982.
- 2. CONTROLLING DIMENSION: INCH.

	М	MILLIMETERS INCHES				
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	1.50	1.63	1.75	0.060	0.064	0.068
A1	0.02	0.06	0.10	0.001	0.002	0.004
b	0.60	0.75	0.89	0.024	0.030	0.035
b1	2.90	3.06	3.20	0.115	0.121	0.126
С	0.24	0.29	0.35	0.009	0.012	0.014
D	6.30	6.50	6.70	0.249	0.256	0.263
E	3.30	3.50	3.70	0.130	0.138	0.145
е	2.20	2.30	2.40	0.087	0.091	0.094
e1	0.85	0.94	1.05	0.033	0.037	0.041
L1	1.50	1.75	2.00	0.060	0.069	0.078
HE	6.70	7.00	7.30	0.264	0.276	0.287
θ	0°	_	10°	0°	-	10°

STYLE 3:

- PIN 1. GATE
- 2. DRAIN 3. SOURCE
- 4. DRAIN

SOLDERING FOOTPRINT*



*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

HDPlus is a trademark of Semiconductor Components Industries, LLC (SCILLC).

ON Semiconductor and are registered trademarks of Semiconductor Components Industries, LLC (SCILLC). SCILLC reserves the right to make changes without further notice to any products herein. SCILLC makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does SCILLC assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. "Typical" parameters which may be provided in SCILLC data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. SCILLC does not convey any license under its patent rights nor the rights of others. SCILLC products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the SCILLC product could create a situation where personal injury or death may occur. Should Buyer purchase or use SCILLC products for any such unintended or unauthorized application, Buyer shall indemnify and hold SCILLC and its officers, employees, subsidiaries, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that SCILLC was negligent regarding the design or manufacture of the part. SCILLC is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor P.O. Box 61312, Phoenix, Arizona 85082–1312 USA Phone: 480–829–7710 or 800–344–3860 Toll Free USA/Canada Fax: 480–829–7709 or 800–344–3867 Toll Free USA/Canada Email: orderlit@onsemi.com

N. American Technical Support: 800–282–9855 Toll Free USA/Canada

Japan: ON Semiconductor, Japan Customer Focus Center 2–9–1 Kamimeguro, Meguro–ku, Tokyo, Japan 153–0051 Phone: 81–3–5773–3850

ON Semiconductor Website: http://onsemi.com

Order Literature: http://www.onsemi.com/litorder

For additional information, please contact your local Sales Representative.